

# DISCRETE POWER & SIGNAL TECHNOLOGIES

# 2N6076

## SILICON PNP SMALL SIGNAL TRANSISTOR

**BVCEO....25 V (Min)** 

hfe.... 100 (Min) @ VCE = 10 V, IC = 10 mA



# **ABSOLUTE MAXIMUM RATINGS** (NOTE 1) **TEMPERATURES**

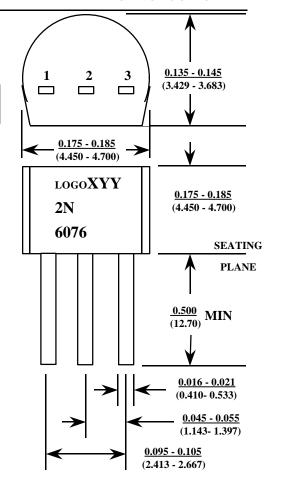
Storage Temperature -55 Degrees C to 150 Degrees C
Operating Junction Temperature 150 Degrees C

## **POWER DISSIPATION** (NOTES 2 & 3)

Total Device Dissipation at TA = 25 Deg C 625 mW

## **VOLTAGES & CURRENT**

VCEO	Collector to Emitter	25 V
VCBO	Collector to Base	25 V
VEBO	Emitter to Base	5 V
IC	Collector Current	500 mA



## **ELECTRICAL CHARACTERISTICS** (25 Degrees C Ambient Temperature unless otherwise stated)

SYM	CHARACTERISTICS	MIN	MAX	UNITS	TEST CONDITIONS
Вусво	Collector to Base Voltage	25		V	Ic = 100 uA
Вусео	Collector to Emitter Voltage	25		V	IC = 10  mA
Вуево	Emitter to Base Voltage	5		V	IE = 10 uA
Ісво	Collector Cutoff Current		100	nA	$V_{CB} = 25 V$
			10	uA	$V_{CB} = 25 V, T=+100^{\circ} C$
ICES	Collector Cutoff Current		100	nA	$V_{CE} = 25 V$
ІЕВО	Emitter Cutoff Current		100	uA	VEB = 3.0 V
hFE	DC Current Gain	100	500		VCE = 10 V $IC = 10 mA$
VCE(sat)	Collector-Emitter Saturation Voltage		0.25	V	IC = 10mA  IB = 1.0mA
VBE(sat)	Base-Emitter Saturation Voltage		0.8	V	IC = 10mA  IB = 1.0mA
VBE(on)	Base -Emitter On Voltage	0.5	1.2	V	VCE = 10 V IC = 10mA



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## SILICON PNP SMALL SIGNAL TRANSISTOR

**ELECTRICAL CHARACTERISTICS** Con't (25 Degrees C Ambient Temperature unless otherwise stated)

SYM	CHARACTERISTICS	MIN	MAX	UNITS	TEST CONDITIONS
Ссь	Output Capacitance	1	13	pF	VCB = 10 V, f = 1 MHz
hfe	Small Signal Current Gain	100	750		VCE = 10 V, IC=10 mA, f=1KHz

## NOTES:

- 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
- 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
- 3. These ratings are based on a maximum junction temperature of 150 degrees C.

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